

General Description

The HM2459A is a monolithic, step-down, switch mode converter with a built-in power MOSFET. It achieves a 0.6A peak-output current over input supply 5.0V-60V with excellent load and line regulation. Current-mode operation provides a fast transient response and eases loop stabilization. Fault condition protections include cycle-by-cycle current limiting and thermal shutdown.

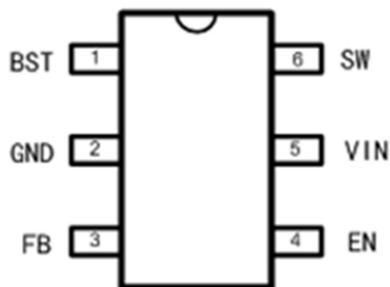
The HM2459A requires a minimal number of readily-available external components.

The HM2459A is available in a SOT23-6 package

Features

- 0.6A Peak Output Current
- 0.9Ω Internal Power MOSFET
- Stable with Low-ESR Ceramic Output Capacitors
- Up to 90% Efficiency
- 0.1μA Shutdown Mode
- Fixed 480kHz Frequency
- Thermal Shutdown
- Cycle-by-Cycle Over-Current Protection
- 5.0V to 60V Operating Input Range
- Max duty 90%
- Available in a SOT23-6 Package

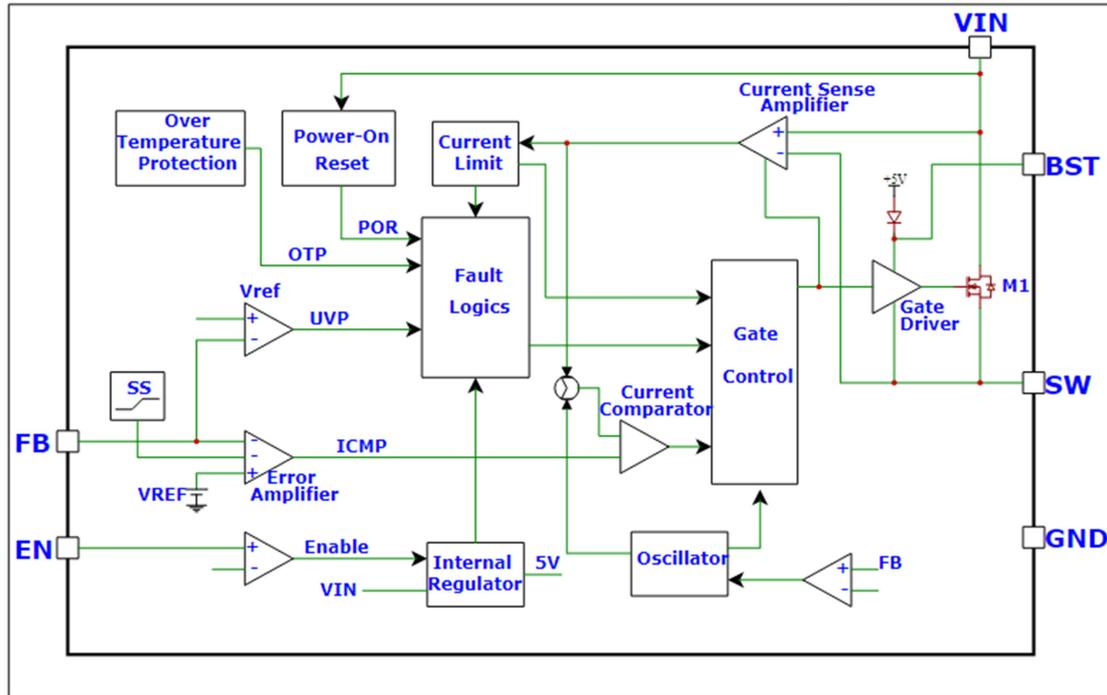
Pin Configurations



Applications

- Power Meters
- Distributed Power Systems
- Battery Chargers
- Pre - Regulator for Linear Regulators
- WLED Drivers

Block



Pin Description

Pin	Name	Description
1	BST	Bootstrap. Connect a capacitor between the SW and BST pins to form a floating supply across the power switch driver. This capacitor drives the power switch's gate above the supply voltage.
2	GND	Ground. Voltage reference for the regulated output voltage. Requires special layout considerations. Isolate this node from the D1 to C1 ground path to prevent switching current spikes from inducing.
3	FB	Feedback. Sets the output voltage. Connect to the tap of an external resistor divider from the output to GND. The frequency fold back comparator lowers the oscillator frequency when the FB voltage is below 250mV to prevent current-limit runaway during a short-circuit fault.
4	EN	On/Off. Pull EN above 1.35V to turn the device ON. For automatic enable, connect to VIN using a 0.1MQ resistor.
5	VIN	Supply Voltage. Requires C1 to prevent large voltage spikes from appearing at the input.
6	SW	Power Switching Output. It is the Drain of the N-Channel power MOSFET to supply power to the output LC filter.

Absolute Maximum Ratings (Note1)

Symbol	Parameter	Rating	Unit
V _{IN}	V _{IN} Supply Voltage (V _{IN} to GND)	-0.3 ~ 60	V
V _{SW}	SW to GND Voltage	-0.3 to V _{IN} +0.3	V
V _{BST}	BST to GND Voltage	V _{SW} - 0.3 ~ V _{SW} +6	V
	All Other Pins	-0.3 ~ 6	V
P _D	Power Dissipation	Internally Limited	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-65 ~ 150	°C
T _{SDR}	Maximum Lead Soldering Temperature (10 Seconds)	260	°C

Note1: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied, Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Thermal Characteristics

Symbol	Parameter	Typical Value	Unit
θ_{JA}	Junction-to-Ambient Resistance in free air (Note 2) SOT-23-6	250	°C/W

Note 2: θ_{JA} is measured with the component mounted on a high effective thermal conductivity test board in free air.

Recommended Operation Conditions (Note3)

Symbol	Parameter	Range	Unit
V _{IN}	V _{IN} Supply Voltage	5.0 ~ 60	V
V _{OUT}	Converter Output Voltage	V _{FB} ~ V _{IN} *85%	V
	Operating Junction Temp	- 40 ~ 125	°C

Note 3: Refer to the typical application circuit

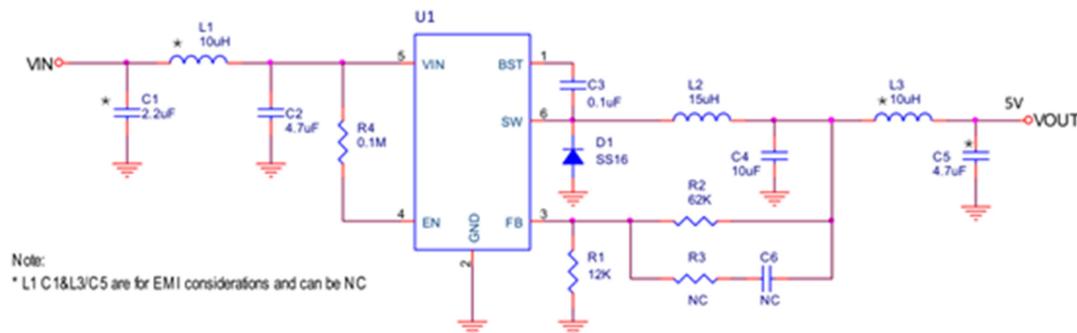
Electrical Characteristics

Unless otherwise specified, these specifications apply over V_{IN} =12V, V_{EN} =3V and T_A = 25°C.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
V _{FB}	Feedback Voltage	5.0 ≤ V _{IN} ≤ 60V	0.790	0.812	0.834	V
I _{FB}	Feedback Current	V _{FB} = 0.85V			0.1	uA
R _{DS(ON)}	Switch-On Resistance			0.9		Ω
I _{SW_LKG}	Switch Leakage	V _{EN} =0V, V _{SW} =0V			1	uA
I _{LIM}	Current Limit			1.35		A
f _{sw}	Oscillator Frequency	V _{FB} =0.6V		480		kHz
f _{sw_F}	Foldback Frequency	V _{FB} =0V		150		kHz
D _{MAX}	Maximum Duty Cycle	V _{FB} =0.6V		90		%
T _{ON}	Minimum ON-Time			100		ns

VUVLO_R	Under-Voltage Lockout Threshold, Rising		3.3	3.73	V
VUVLO_F	Under-Voltage Lockout Threshold, Falling	2.6	3.0		V
VUVLO_HYS	Under-Voltage Lockout Threshold, Hysteresis		0.3		V
VEN_R	EN Threshold, Rising		1.35		V
VEN_F	EN Threshold, Falling		1.0		V
VEN_HYS	EN Threshold, Hysteresis		350		mV
IEN	EN Input Current	VEN=2V	3.0		uA
		VEN=0V	0.1		uA
IS	Supply Current (Shutdown)	VEN=0V	0.1	1	uA
IQ	Supply Current (Quiescent)	VEN=2V, VFB=1V	0.7	0.9	mA
TSD	Thermal Shutdown		165		°C
TSD_HYS	Thermal Shutdown Hysteresis		20		°C

Typical Application Circuit



OPERATION

The HM2459A is a current mode buck regulator. That is, the EA output voltage is proportional to the peak inductor current. At the beginning of a cycle, M1 is off. The EA output voltage is higher than the current sense amplifier output, and the current comparator's output is low. The rising edge of the 480 kHz CLK signal sets the RS Flip-Flop. Its output turns on M1 thus connecting the SW pin and inductor to the input supply.

The increasing inductor current is sensed and amplified by the Current Sense Amplifier. Ramp compensation is summed to the Current Sense Amplifier output and compared to the Error Amplifier output by the PWM Comparator. When the sum of the Current Sense Amplifier output and the Slope Compensation signal exceeds the EA output voltage, the RS Flip-Flop is reset and M1 is turned off. The external Schottky rectifier diode (D1) conducts the inductor current.

If the sum of the Current Sense Amplifier output and the Slope Compensation

signal does not exceed the EA output for a whole cycle, then the falling edge of the CLK resets the Flip-Flop.

The output of the Error Amplifier integrates the voltage difference between the feedback and the 0.812V bandgap reference.

The polarity is such that lower than 0.812V FB pin voltage increases the EA output voltage. Since the EA output voltage is proportional to the peak inductor current, an increase in its voltage also increases current delivered to the output.

Application Information

Setting Output Voltage

The external resistor divider sets the output voltage (see the Typical Application schematic). Table 1 lists resistors for common output voltages. The feedback resistor (R2) also sets the feedback loop bandwidth with the internal compensation capacitor (see Figure 1) R1is:

$$R1 = \frac{R2}{\frac{V_{OUT}}{0.812V} - 1}$$

Table 1: Resistor Selection for Common output voltages

VOUT(V)	R1(K Ω)	R2(K Ω)
1.8	102(1%)	124(1%)
2.5	59(1%)	124(1%)
3.3	40.2(1%)	124(1%)
5	23.7(1%)	124(1%)

Selecting the Inductor

Use an inductor with a DC current rating at least 25% percent higher than the maximum load current for most applications. For best efficiency, the inductor's DC resistance should be less than 200m Ω .

For most designs, the required inductance value can be derived from the following equation.

$$L = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times \Delta I_L \times f_{SW}}$$

Where ΔI_L is the inductor ripple current.

Choose the inductor ripple current to be 30% of the maximum load current. The maximum inductor peak current is:

$$I_{L(MAX)} = I_{LOAD} + \frac{\Delta I_L}{2}$$

Under light-load conditions (below100mA), use a larger inductance to improve efficiency.

Selecting the Input Capacitor

The input capacitor reduces the surge current drawn from the input supply and the switching noise from the device. The input capacitor impedance at the switching frequency should be less than the input source impedance to prevent high-frequency-switching current from passing through the input. Use ceramic capacitors with X5R or X7R dielectrics for their low ESRs and small temperature coefficients. For most applications, a 4.7 μ F capacitor will sufficient.

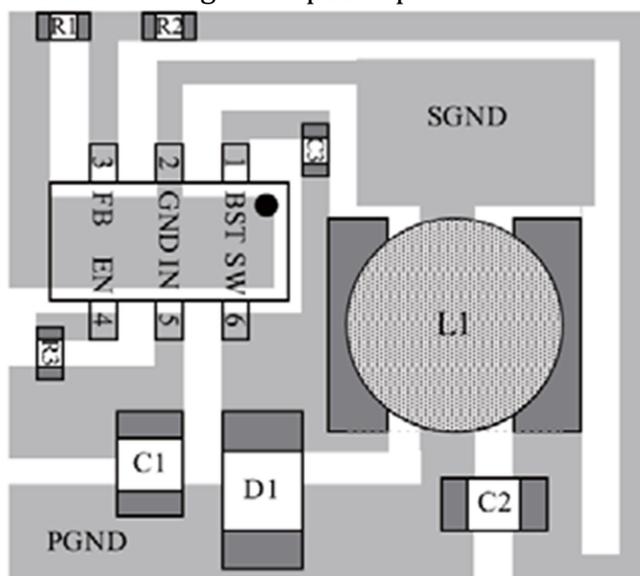
Selecting the Output Capacitor

The output capacitor keeps the output voltage ripple small and ensures feedback loop stability. The output capacitor impedance should be low at the switching frequency. Use ceramic capacitors with X5R or X7R dielectrics for their low ESR characteristics. For most applications, a 22 μ F ceramic capacitor will sufficient.

PCB Layout Guide

PCB layout is very important to stability. Please follow these guidelines and use Figure 2 as reference.

- 1) Keep the path of switching current short and minimize the loop area formed by the input capacitor, high-side MOSFET and Schottky diode.
- 2) Keep the connection from the power ground→Schottky diode→SW pin as short and wide as possible.
- 3) Ensure all feedback connections are short and direct. Place the feedback resistors and compensation components as close to the chip as possible.
- 4) Route SW away from sensitive analog areas such as FB.
- 5) Connect IN, SW, and especially GND to large copper areas to cool the chip for improved thermal performance and long-term reliability For single layer PCBs, avoid soldering the exposed pad.



Package Information

SOT23-6 Package Outline Dimensions

